TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

T C 7 M A R 2 2 4 5 F K

Low-Voltage Octal Bus Transceiver with 3.6 V Tolerant Inputs and Outputs

The TC7MAR2245FK is a high performance CMOS octal bus transceiver. Designed for use in 1.8, 2.5 or 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6 V.

The direction of data transmission is determined by the level of the DIR inputs. The OE inputs can be used to disable the device so that the busses are effectively isolated.

The 26- Ω series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.

Features

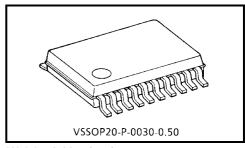
- 26- Ω series resistors on outputs.
- Low voltage operation: $VCC = 1.8 \sim 3.6 V$
- High speed operation:
 - $t_{pd} = 4.4 \text{ ns} (max) (V_{CC} = 3.0 \sim 3.6 \text{ V})$ $t_{pd} = 5.6 \text{ ns} (max) (V_{CC} = 2.3 \sim 2.7 \text{ V})$ $t_{pd} = 9.8 \text{ ns} (max) (V_{CC} = 1.8 \text{ V})$
- 3.6 V tolerant inputs and outputs.
- Bidirectional interface between 2.5 V and 3.3 V signals. (*1)
- Power down protection is provided on all inputs and outputs. (*2)
- Supports live insertion/withdrawal (*3)

*1: Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.

- *2: All floating (high impedance) bus terminal must have their input level fixed by means of pull up or pull down resistors.
- *3: To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

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Weight: 0.03 g (typ.)

- Output current: $IOH/IOL = \pm 12 \text{ mA} (min) (VCC = 3.0 \text{ V})$ $IOH/IOL = \pm 8 \text{ mA} \text{ (min)} (VCC = 2.3 \text{ V})$ $IOH/IOL = \pm 4 \text{ mA} \text{ (min)} (VCC = 1.8 \text{ V})$
- Latch-up performance: ±300 mA
 - ESD performance: Machine model > ± 200 V Human body model > ± 2000 V

• Package: VSSOP (US20)

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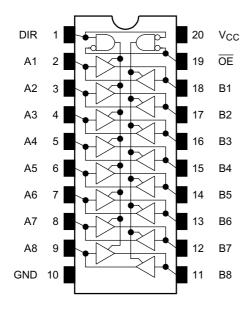
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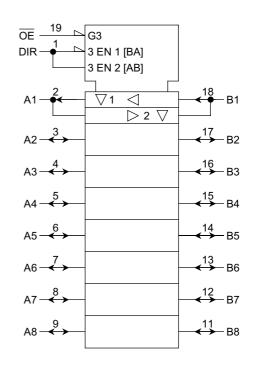
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Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inp	uts	Outputs	Fund	ction
ŌĒ	DIR	Outputs	A-Bus	B-Bus
L	L	A = B	Output	Input
L	Н	B = A	Input	Output
Н	Х	Z	Z	

X: Don't care

Z: High impedance

Maximum Ratings

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5~4.6	V	
DC input voltage (DIR, OE)	V _{IN}	-0.5~4.6	V	
DC bus I/O voltage	Vuo	-0.5~4.6 (Note1)	V	
DC bus 1/O voltage	V _{I/O}	-0.5~V _{CC} + 0.5 (Note2)	v	
Input diode current	I _{IK}	-50	mA	
Output diode current	I _{OK}	±50 (Note3)	mA	
DC output current	IOUT	±50	mA	
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	-65~150	°C	

Note1: Off-state

Note2: High or low state. IOUT absolute maximum rating must be observed.

Note3: V_{OUT} < GND, V_{OUT} > V_{CC}

Recommended Operating Range

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	1.8~3.6	V	
Supply Voltage	VCC	1.2~3.6 (Note4)	v	
Input voltage (DIR, OE)	V _{IN}	-0.3~3.6	V	
Bus I/O voltage	V _{I/O}	0~3.6 (Note5)	V	
Bus i/O voltage	VI/O	0~V _{CC} (Note6)	v	
		±12 (Note7)		
Output current	I _{OH} /I _{OL}	±8 (Note8)	mA	
		±4 (Note9)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note10)	ns/V	

Note4: Data retention only

Note5: Off-state

Note6: High or low state

Note7: V_{CC} = 3.0~3.6 V

Note8: V_{CC} = 2.3~2.7 V

Note9: $V_{CC} = 1.8 V$

Note10: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics (Ta = -40~85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characteristics		Symbol	Test Condition			Min	Max	Unit
Characte	liouoo	0,			$V_{CC}(V)$		max	•
Input voltage	High level	VIH		—	2.7~3.6	2.0	_	V
input voltage	Low level	VIL		_	2.7~3.6	_	0.8	v
				I _{OH} = −100 μA	2.7~3.6	V _{CC} - 0.2	_	
	High level	VoH	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -6 \text{ mA}$	2.7	2.2	_	
Output voltage	-			$I_{OH} = -8 \text{ mA}$	3.0	2.4	—	
				I _{OH} = -12 mA	3.0	2.2		V
			$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 100 μA	2.7~3.6	_	0.2	-
	Low level	Max		$I_{OL} = 6 \text{ mA}$	2.7	_	0.4	
	Low level	V _{OL}		I _{OL} = 8 mA	3.0	_	0.55	
				I _{OL} = 12 mA	3.0		0.8	
Input leakage curr	ent	I _{IN}	V _{IN} = 0~3.6 V	·	2.7~3.6		±5.0	μA
3-state output off-state current		I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \sim 3.6 \text{ V}$		2.7~3.6	_	±10.0	μA
Power off leakage	current	IOFF	V _{IN} , V _{OUT} = 0~3.6 V		0		10.0	μA
			V _{IN} = V _{CC} or GND		2.7~3.6	_	20.0	
Quiescent supply	current	Icc	$V_{CC} \stackrel{\scriptstyle \leq}{=} (V_{IN},V_{OUT}) \stackrel{\scriptstyle \leq}{=}$	3.6 V	2.7~3.6	_	±20.0	μA
Increase in I _{CC} pe	r input	∆l _{CC}	$V_{IH} = V_{CC} - 0.6 V$		2.7~3.6	_	750	

DC Characteristics (Ta = -40~85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Character	ristics	Symbol	Test	Test Condition		Test Condition		Min	Max	Unit
Input voltage	High level	VIH		_	2.3~2.7	1.6	_	V		
Input voltage	Low level	VIL		_	2.3~2.7		0.7	v		
				I _{OH} = -100 μA	2.3~2.7	V _{CC} - 0.2	_			
	High level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -4 \text{ mA}$	2.3	2.0	_			
Output voltage	-			$I_{OH} = -6 \text{ mA}$	2.3	1.8	_	V		
				$I_{OH} = -8 \text{ mA}$	2.3	1.7	_			
			V_{OL} $V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 100 μA	2.3~2.7	_	0.2			
	Low level	V _{OL}		I _{OL} = 6 mA	2.3	_	0.4			
				$I_{OL} = 8 \text{ mA}$	2.3	_	0.6			
Input leakage curre	ent	I _{IN}	V _{IN} = 0~3.6 V		2.3~2.7	_	±5.0	μA		
2 state output off a	tata aurrant	1	$V_{IN} = V_{IH} \text{ or } V_{IL}$		2.3~2.7	_	±10.0			
3-state output off-state current		loz	V _{OUT} = 0~3.6 V	V _{OUT} = 0~3.6 V			±10.0	μA		
Power off leakage	current	I _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0	_	10.0	μA		
Quiescent supply of			$V_{IN} = V_{CC}$ or GND		2.3~2.7	—	20.0	μA		
Quiescent supply (Icc	$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3$	$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6 \text{ V}$		—	±20.0	μΑ		

DC Characteristics (Ta = $-40 \sim 85^{\circ}$ C, 1.8 V $\leq V_{CC} < 2.3$ V)

Characteristics		Symbol	Test Condition			Min	Max	Unit		
Characteris	51105	Symbol	Test	Condition	$V_{CC}(V)$	IVIIII	IVIAX	Unit		
Input voltage	High level	VIH		—	1.8~2.3	$0.7 \times V_{CC}$		V		
mput voltage	Low level	V _{IL}		—	1.8~2.3		$0.2 \times V_{CC}$	v		
	High level	Vон	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -100 μA	1.8	V _{CC} - 0.2				
Output voltage	put voltage			$I_{OH} = -4 \text{ mA}$	1.8	1.4		V		
		ow level V _{OL}	V_{OL} $V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 100 μA	1.8	_	0.2			
	LOWIEVEI			$I_{OL} = 4 \text{ mA}$	1.8		0.3			
Input leakage currer	nt	I _{IN}	V _{IN} = 0~3.6 V		1.8		±5.0	μA		
3-state output off-state current		I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \sim 3.6 \text{ V}$		1.8		±10.0	μA		
Power off leakage c	urrent	I _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		V _{IN} , V _{OUT} = 0~3.6 V		0	_	10.0	μA
Quiescent supply cu	urrent		$V_{IN} = V_{CC}$ or GND		1.8	_	20.0	μA		
Quiescent supply ct		Icc	$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6 \text{ V}$		1.8	_	±20.0	μA		

AC Characteristics (Ta = -40~85°C, Input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Symbol Test Condition		Min	Max	Unit
	Cymzei		$V_{CC}(V)$		Мах	Onit
	+		1.8	1.5	9.8	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	0.8	5.6	ns
	t _{pHL}		3.3 ± 0.3	0.6	4.4	
3-state output enable time	+		1.8	1.5	9.8	
	t _{pZL} t _{pZH}	Figure 1, Figure 3	2.5 ± 0.2	0.8	6.6	ns
			3.3 ± 0.3	0.6	5.0	
	t . –		1.8	1.5	8.5	
3-state output disable time	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	2.5 ± 0.2	0.8	4.7	ns
			3.3 ± 0.3	0.6	4.2	
	+		1.8	_	0.5	
Output to output skew	t _{osLH}	(Note11)	2.5 ± 0.2	_	0.5	ns
	t _{osHL}		3.3 ± 0.3		0.5	

For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note11: This parameter is guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, Input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note12)	1.8	0.15	
Quiet output maximum dynamic V_{OL}	V _{OLP}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note12)	2.5	0.25	V
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note12)	3.3	0.35	
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note12)	1.8	-0.15	
Quiet output minimum dynamic V_{OL}	V _{OLV}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note12)	2.5	-0.25	V
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note12)	3.3	-0.35	
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note12)	1.8	1.55	
Quiet output minimum dynamic V_{OH}	V _{OHV}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note12)	2.5	2.05	V
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note12)	3.3	2.65	

Note12: This parameter is guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	DIR, OE		1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}	An, Bn		1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (No	ote13)	1.8, 2.5, 3.3	20	pF

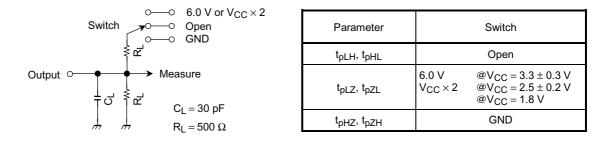
Note13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

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AC Test Circuit





AC Waveform

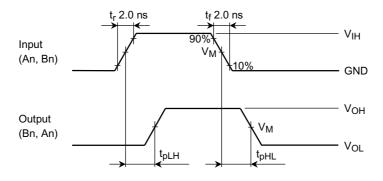


Figure 2 t_{pLH}, t_{pHL}

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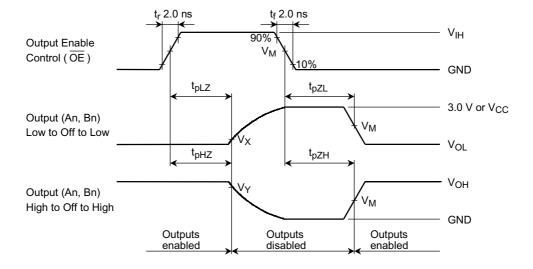


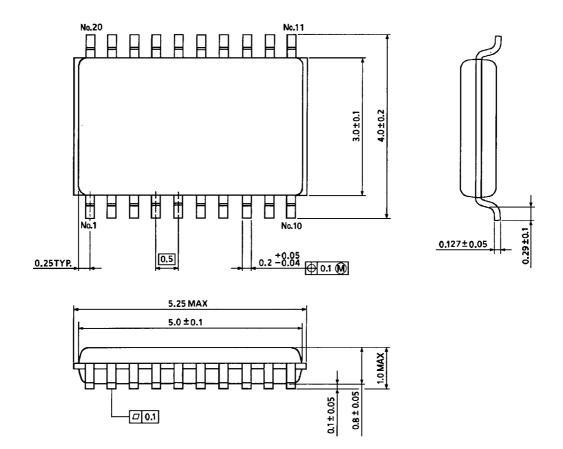
Figure 3	t _{pLZ} , 1	^t pHZ,	t _{pZL} ,	t _{pZH}
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Symbol		V _{CC}	
Symbol	$3.3\pm0.3~\text{V}$	$2.5\pm0.2~\text{V}$	1.8 V
VIH	2.7 V	V _{CC}	V _{CC}
VM	1.5 V	V _{CC} /2	V _{CC} /2
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V

Package Dimensions

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)